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Standard Practice for Tissue Cryosection Analysis with SIMS¹

This standard is issued under the fixed designation E 1880; the number immediately following the designation indicates the year of original adoption or, in the case of revision, the year of last revision. A number in parentheses indicates the year of last reapproval. A superscript epsilon (ϵ) indicates an editorial change since the last revision or reapproval.

1. Scope

1.1 This practice provides the Secondary Ion Mass Spectrometry (SIMS) analyst with a method for analyzing tissue cryosections in the imaging mode of the instrument. This practice is suitable for frozen-freeze-dried and frozen-hydrated cryosection analysis.

1.2 This practice does not describe methods for optimal freezing of the specimen for immobilizing diffusible chemical species in their native intracellular sites.

1.3 This practice does not describe methods for obtaining cryosections from a frozen specimen.

1.4 This practice is not suitable for any plastic embedded tissues.

1.5 This standard does not purport to address all of the safety concerns, if any, associated with its use. It is the responsibility of the user of this standard to establish appropriate safety and health practices and determine the applicability of regulatory limitations prior to use.

2. Referenced Documents

2.1 ASTM Standards:

E 673 Terminology Related to Surface Analysis²

3. Terminology

3.1 Definitions:

3.1.1 See Terminology E 673 for definitions of terms used in SIMS.

4. Summary of Practice

4.1 This practice describes a method for the analysis of tissue cryosections with SIMS. Tissue cryosections for SIMS analysis need to be mounted flat on an electrically conducting substrate. Cryosections should remain flat and adhere well to the substrate for SIMS analysis. This is achieved by pressing frozen cryosections into an indium substrate. Indium, being a malleable metal (Moh hardness = 1.2, Young's modulus = 10.6 GPa), provides a "cushion" for pressing and holding the frozen cryosections flat for SIMS analysis. Indium substrates are prepared by pressing sheet indium onto a polished silicon wafer. An approximately 1 μ m thick layer of indium (99.999 % purity) is then vapor deposited on this surface. This

top layer provides "fluffy" indium that helps in holding cryosections flat for SIMS analysis.

5. Significance and Use

5.1 Pressing cryosections flat onto a conducting substrate has been one of the most challenging problems in SIMS analysis of cryogenically prepared tissue specimens. Frozen cryosections often curl or peel off, or both, from the substrate during freeze-drying. The curling of cryosections results in an uneven sample surface for SIMS analysis. Furthermore, if freeze-dried cryosections are not attached tightly to the substrate, the impact of the primary ion beam may result in further curling and even dislodging of the cryosection from the substrate. These problems render SIMS analysis difficult, frustrating and time consuming. The use of indium as a substrate for pressing cryosections flat has provided a practical approach for analyzing cryogenically prepared tissue specimens.³

5.2 The procedure described herein has been successfully used for SIMS imaging of calcium transport in intestinal tissue.^{4,5}

5.3 The procedure described here is amenable to soft tissues of both animal and plant origin.

6. Apparatus

6.1 The procedure described here can be used for tissue cryosection analysis with virtually any SIMS instrument.

6.2 A cold stage in the SIMS instrument is needed to analyze frozen-hydrated specimens.⁶

7. Procedure

7.1 Prepare the indium substrate by pressing sheet indium onto polished silicon wafer pieces of approximately 15 to 25 mm^2 surface area, which can be irregularly shaped. Next,

¹ This practice is under the jurisdiction of ASTM Committee E-42 on Surface Analysis and is the direct responsibility of Subcommittee E42.06 on SIMS.

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² Annual Book of ASTM Standards, Vol 03.06.

³ Sod, E. W., Crooker, A. R., and Morrison, G. H., "Biological Cryosection Preparation and Practical Ion Yield Evaluation for Ion Microscopic Analysis," *Journal of Microscopy (Oxford)*, Vol 160, 1990, p. 55.

⁴ Chandra, S., Fullmer, C. S., Smith, C. A., Wasserman, R. H., and Morrison, G. H. "Ion Microscopic Imaging of Calcium Transport in the Intestinal Tissue of Vitamin D-deficient and Vitamin D-replete Chickens: A⁴⁴Ca Stable Isotope Study," *Proceedings of the National Academy of Sciences (USA)*, Vol 87, 1990, p. 5715.

⁵ Chandra, S., and Morrison, G. H., "Sample Preparation of Animal Tissues and Cell Cultures for Secondary Ion Mass Spectrometry (SIMS) Microscopy," *Biology of the Cell*, Vol 74, 1992, p. 31.

⁶ Chandra, S., Bernius, M. T., and Morrison, G. H., "Intracellular Localization of Diffusible Elements in Frozen-hydrated Biological Specimens with Ion Microscopy," *Analytical Chemistry*, Vol 58, 1986, p. 493.

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vapor deposit an approximately 1 μ m thick layer of high purity (99.999 %) indium onto the pressed indium sheet. The high purity of indium is emphasized only due to the fact that it should not impart any significant contamination to the sample. The vapor deposition can be achieved by vacuum-based processes such as evaporation from a heated filament or sputtering from an indium target. The indium substrates are now ready for use.

7.1.1 Chill an individual indium substrate by immersing it into liquid nitrogen prior to its use for pressing cryosections. Quickly transfer the indium substrate to the cryomicrotome and keep at the desired temperature of cryosectioning. Place a frozen tissue cryosection on the indium substrate and gently press by using a new chilled silicon piece. Make sure that the polished surface of the top silicon piece is used to press the cryosection onto indium substrate in order to avoid introducing the irregular topography of the rough silicon surface. Remove the top silicon piece by sliding it off using chilled tweezers. The pressed frozen cryosection on the indium substrate is now ready for frozen-hydrated analysis with a cold stage in the SIMS instrument. Alternatively, the pressed cryosection on the indium substrate can be freeze-dried by transferring the indium substrate to a freeze-drier. 7.1.2 Upon completion of freeze-drying, the freeze-drier should be opened by introducing dry gasses (N_2 , Ar, etc.) in order to avoid rehydration of tissue sections. The indium substrates containing freeze-dried tissue sections should be quickly transferred to a desiccator for storage. The freeze-dried cryosections are now ready for SIMS analysis.

7.1.3 Depending on the need of a particular SIMS analysis, the freeze-dried cryosections may be analyzed directly or gold coated to enhance electrical conductivity.

7.1.4 A quick visual inspection of the cryosection surface should be made prior to its insertion into the sample chamber of the SIMS instrument. A reflected light microscope can be used to observe any folds, ripples or loosely attached regions in the section. At this stage, it is always desirable to "repress" the freeze-dried section gently into the indium with a polished silicon piece. It is also desirable to remove the loosely attached pieces of tissue section from the substrate by using tweezers.

7.1.5 Correlative morphological information to compliment the SIMS analysis can be made by using adjacent cryosections for optical microscopy and SIMS analysis.⁴

8. Keywords

8.1 SIMS

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